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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/945,553	08/30/2001	Fernando Gonzalez	303.775USI	1842
21186	7590 12/28/2004		EXAMINER	
SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.			FOURSON III, GEORGE R	
P.O. BOX 293	38			
MINNEAPOL	JIS, MN 55402		ART UNIT	PAPER NUMBER
			2823	
•			DATE MAILED, 12/20/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
Office Action Summany	09/945,553	GONZALEZ ET AL.			
Office Action Summary	Examiner	Art Unit	لمما		
	George Fourson	2823	pr		
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the o	correspondence addres.	s		
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply if NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be till within the statutory minimum of thirty (30) day ill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	mely filed ys will be considered timely. In the mailing date of this communicing (35 U.S.C. § 133).	nication.		
Status					
1) Responsive to communication(s) filed on 14 O	ctober 2004.				
2a)⊠ This action is <b>FINAL</b> . 2b)□ This	action is non-final.				
3) Since this application is in condition for allowar	nce except for formal matters, pr	osecution as to the me	rits is		
closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 4	53 O.G. 213.			
Disposition of Claims					
4) Claim(s) 1-66 is/are pending in the application.					
4a) Of the above claim(s) <u>2-4,8,13,16,23-30 an</u>		onsideration.			
5) Claim(s) is/are allowed.	<del></del>				
6) Claim(s) 1,5,6,9-12,14,15,17-22 and 31-33 is/a	are rejected.				
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/o	r election requirement.				
Application Papers	·				
9) The specification is objected to by the Examine	rf.				
10)☐ The drawing(s) filed on is/are: a)☐ acc	epted or b) $\square$ objected to by the	Examiner.			
Applicant may not request that any objection to the	drawing(s) be held in abeyance. Se	ee 37 CFR 1.85(a).			
Replacement drawing sheet(s) including the correct	•				
11)☐ The oath or declaration is objected to by the Ex	caminer. Note the attached Office	e Action or form PTO-1	52.		
Priority under 35 U.S.C. § 119					
12) ☐ Acknowledgment is made of a claim for foreign a) ☐ All b) ☐ Some * c) ☐ None of:	priority under 35 U.S.C. § 119(a	a)-(d) or (f).			
1. Certified copies of the priority document	s have been received				
2. Certified copies of the priority document		tion No			
3.☐ Copies of the certified copies of the prior			је		
application from the International Bureau	· •				
* See the attached detailed Office action for a list of the certified copies not received.					
Attachment(s)  1) Notice of References Cited (PTO-892)	4) 🔲 Interview Summar	v (PTO-413)			
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail D	Date			
<ol> <li>Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)</li> <li>Paper No(s)/Mail Date 200409 € 22</li> </ol>	5) Notice of Informal 6) Other:	Patent Application (PTO-152	<b>(</b> )		
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The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.

Claims 1,5,6,9-12,14 and 15 are rejected under 35 U.S.C. 103(a) as being unpatentable over the combination of applicant's admitted prior art (AAPA) and Mitani et al.

Applicant admits in the instant specification, pages 1-3, formation of a polycide gate stack followed by patterning and oxidation of the polysilicon portion of the stack. The process of AAPA does not include presence of gaseous NF<sub>3</sub>.

Mitani et al discloses oxidation of polysilicon gate material in an ambient comprising NF<sub>3</sub> as a method of introducing F into the channel region of a MOSFET (col.41, lines 12-18).

Mitani et al discloses one aim of the process is introduction of the halogen element contained in the sidewall insulating films formed on the sidewalls of the gate electrode into the gate electrode (col.3, lines 65+) to obtain a desired doping profile in the channel region including a profile in which the F concentration near the edges of the channel region is higher than that in the middle of the channel region (col.42, lines 4+). Also see the 26<sup>th</sup> embodiment (col.41) in which an insulating film is formed on the sidewall of a polysilicon gate electrode by thermal oxidation of polysilicon in the presence of NF<sub>3</sub> to introduce F into the channel region of a FET.

It would have been within the scope of one of ordinary skill in the art to combine the teachings of AAPA and Mitani et al to enable the oxidation step of AAPA to be performed and further to achieve the introduction of F according to the teachings of Mitani et al to achieve a desired profile of F in the channel region of the resulting MOSFET. The presence of the metal restricting oxidation of the top surface of the

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poly region would be understood by one of ordinary skill in the art to result in the profile in which the F concentration is higher at the edges than in the middle of the channel region.

Applicant's argument that in the process of Mitani et al the gate structure does not contain metal is addressed in the statement of the rejection above.

Claims 17 and 18-22 are rejected under 35 U.S.C. 103(a) as being unpatentable over AAPA in combination with Mitani et al as applied to claims 1,5,6,9-12,14 and 15 above, and further in view of Cunningham.

AAPA in combination with Mitani et al does not include sidewall formation or metal nitride barrier layer formation.

Cunningham discloses sidewall formation after polysilicon oxidation and metal nitride barrier layer formation in a polycide gate formation process (abstract and [0030]).

It would have been within the scope of one of ordinary skill in the art to combine the teachings of AAPA, Mitani et al and Cunningham to enable the polycide gate structure of AAPA to be formed according to the teachings of Cunningham related to obtaining greater tolerance to higher temperature annealing.

Claims 31-33 are rejected under 35 U.S.C. 103(a) as being unpatentable over AAPA in combination with Mitani et al as applied to claims 1,5,6,9-12,14 and 15 above, and further in view of Jain et al.

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AAPA and Mitani et al do not disclose presence of NF<sub>3</sub> during gate patterning.

Jain et al discloses patterning of layers to form a polycide gate electrode using NF<sub>3</sub> gas (col.2, lines 13-22).

It would have been within the scope of one of ordinary skill in the art to combine the teachings of AAPA, Mitani et al and Jain et al to enable the step of patterning the gate stack of AAPA to be performed and furthermore to enable removal of the ARC as disclosed by Jain (see abstract).

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action.

Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry of a general nature or relating to the status of this application should be directed to the Group Receptionist whose telephone number is (703) 308-0956 until 2/4/04. See MPEP 203.08.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to examiner George Fourson whose telephone number is (571)272-1860. The examiner can normally be reached on Monday through Friday.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri, can be reached on (571)272-1855. The fax number for this group is (571)273-0224 and the customer service number for group 2800 is 571-272-2800. Updates can be found at http://www.uspto.gov/web/info/2800.htm.

George Fourson Primary Examiner Art Unit 2823

GFourson December 22, 2004